DISCRETE SEMICONDUCTORS

DATA SHEET

PDTA124T series PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = open

Product data sheet Supersedes data of 2004 May 05 2004 Aug 04



PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = open

PDTA124T series

FEATURES

- Built-in bias resistors
- · Simplified circuit design
- Reduction of component count
- · Reduced pick and place costs.

APPLICATIONS

- General purpose switching and amplification
- · Inverter and interface circuits
- Circuit driver.

QUICK REFERENCE DATA

| SYMBOL | PARAMETER | TYP. | MAX. | UNIT |
|------------------|---------------------------|------|------|------|
| V _{CEO} | collector-emitter voltage | _ | -50 | V |
| Io | output current (DC) | _ | -100 | mA |
| R1 | bias resistor | 22 | _ | kΩ |
| R2 | open | _ | _ | _ |

DESCRIPTION

PNP resistor-equipped transistor (see "Simplified outline, symbol and pinning" for package details).

PRODUCT OVERVIEW

| TVDE NUMBER | PAC | KAGE | MARKING CORE | NDN COMPLEMENT |
|-------------|---------------|--------|--------------------|----------------|
| TYPE NUMBER | PHILIPS | EIAJ | MARKING CODE | NPN COMPLEMENT |
| PDTA124TE | SOT416 | SC-75 | 3R | PDTC124TE |
| PDTA124TEF | SOT490 | SC-89 | 24 | PDTC124TEF |
| PDTA124TK | SOT346 | SC-59 | 59 | PDTC124TK |
| PDTA124TM | SOT883 | SC-101 | DJ | PDTC124TM |
| PDTA124TS | SOT54 (TO-92) | SC-43 | TA124T | PDTC124TS |
| PDTA124TT | SOT23 | _ | *AE ⁽¹⁾ | PDTC124TT |
| PDTA124TU | SOT323 | SC-70 | *7B ⁽¹⁾ | PDTC124TU |

Note

^{1. * =} p: Made in Hong Kong.

^{* =} t: Made in Malaysia.

^{* =} W: Made in China.

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SIMPLIFIED OUTLINE, SYMBOL AND PINNING

| TYPE NUMBER | CIMPLIFIED OUTLINE AND CYMPOL | | PINNING |
|--|----------------------------------|-------|------------------------------|
| TYPE NUMBER | SIMPLIFIED OUTLINE AND SYMBOL | PIN | DESCRIPTION |
| PDTA124TS | 1 R1 R1 3 MAM352 | 1 2 3 | base collector emitter |
| PDTA124TE PDTA124TEF PDTA124TK PDTA124TT PDTA124TU | 3 1 R1 3 1 Top view MDB272 | 1 2 3 | base emitter collector |
| PDTA124TM | 2 R1 3 1 Bottom view MDB268 | 1 2 3 | base emitter collector |

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ORDERING INFORMATION

| TYPE | PACKAGE | | | | | | | | |
|------------|---------|---|---------|--|--|--|--|--|--|
| NUMBER | NAME | DESCRIPTION | VERSION | | | | | | |
| PDTA124TE | _ | plastic surface mounted package; 3 leads | SOT416 | | | | | | |
| PDTA124TEF | _ | plastic surface mounted package; 3 leads | SOT490 | | | | | | |
| PDTA124TK | _ | plastic surface mounted package; 3 leads | SOT346 | | | | | | |
| PDTA124TM | - | leadless ultra small plastic package; 3 solder lands; body $1.0 \times 0.6 \times 0.5$ mm | SOT883 | | | | | | |
| PDTA124TS | _ | plastic single-ended leaded (through hole) package; 3 leads | SOT54 | | | | | | |
| PDTA124TT | - | plastic surface mounted package; 3 leads | SOT23 | | | | | | |
| PDTA124TU | - | plastic surface mounted package; 3 leads | SOT323 | | | | | | |

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------|-------------------------------|--------------------------|------|------|------|
| V _{CBO} | collector-base voltage | open emitter | _ | -50 | V |
| V _{CEO} | collector-emitter voltage | open base | _ | -50 | V |
| V_{EBO} | emitter-base voltage | open collector | - | -5 | V |
| Io | output current (DC) | | _ | -100 | mA |
| I _{CM} | peak collector current | | _ | -100 | mA |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C | | | |
| | SOT23 | note 1 | _ | 250 | mW |
| | SOT54 | note 1 | _ | 500 | mW |
| | SOT323 | note 1 | _ | 200 | mW |
| | SOT346 | note 1 | _ | 250 | mW |
| | SOT416 | note 1 | _ | 150 | mW |
| | SOT490 | notes 1 and 2 | _ | 250 | mW |
| | SOT883 | notes 2 and 3 | _ | 250 | mW |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| T _j | junction temperature | | _ | 150 | °C |
| T _{amb} | operating ambient temperature | | -65 | +150 | °C |

Notes

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60 μm copper strip line.

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THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|----------------------|---|---------------|-------|------|
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | | |
| | SOT23 | note 1 | 500 | K/W |
| | SOT54 | note 1 | 250 | K/W |
| | SOT323 | note 1 | 625 | K/W |
| | SOT346 | note 1 | 500 | K/W |
| | SOT416 | note 1 | 833 | K/W |
| | SOT490 | notes 1 and 2 | 500 | K/W |
| | SOT883 | notes 2 and 3 | 500 | K/W |

Notes

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60 μm copper strip line.

CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|--------------------|--------------------------------------|--|------|------|------|------|
| I _{CBO} | collector-base cut-off current | $V_{CB} = -50 \text{ V}; I_E = 0 \text{ A}$ | _ | _ | -100 | nA |
| I _{CEO} | collector-emitter cut-off current | $V_{CE} = -30 \text{ V}; I_B = 0 \text{ A}$ | _ | _ | -1 | μΑ |
| | | $V_{CE} = -30 \text{ V}; I_{B} = 0 \text{ A};$ $T_{j} = 150 \text{ °C}$ | _ | _ | -50 | μΑ |
| I _{EBO} | emitter-base cut-off current | $V_{EB} = -5 \text{ V}; I_{C} = 0 \text{ A}$ | _ | - | -100 | nA |
| h _{FE} | DC current gain | $V_{CE} = -5 \text{ V}; I_{C} = -1 \text{ mA}$ | 100 | - | _ | |
| V _{CEsat} | collector-emitter saturation voltage | $I_C = -10 \text{ mA}; I_B = -0.5 \text{ mA}$ | _ | _ | -150 | mV |
| R1 | input resistor | | 15.4 | 22 | 28.6 | kΩ |
| C _c | collector capacitance | $I_E = I_e = 0 \text{ A}; V_{CB} = -10 \text{ V};$ f = 1 MHz | - | _ | 3 | pF |

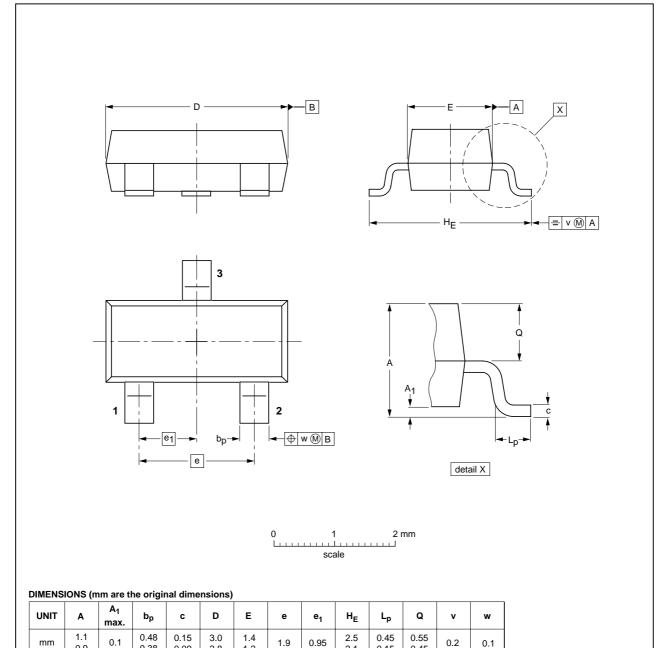
PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = open

PDTA124T series

PACKAGE OUTLINES

Plastic surface-mounted package; 3 leads

SOT23



| OUTLINE | | REFER | ENCES | EUROPEAN | ISSUE DATE | |
|---------|-----|----------|-------|------------|-----------------------------------|--|
| VERSION | IEC | JEDEC | JEITA | PROJECTION | ISSUE DATE | |
| SOT23 | | TO-236AB | | | -04-11-04- 06-03-16 | |

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0.38

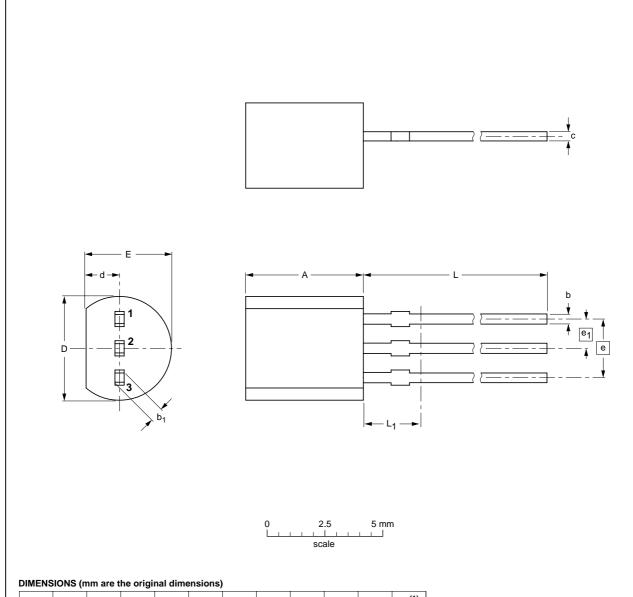
0.9

PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = open

PDTA124T series

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



| UNIT | Α | b | b ₁ | С | D | d | E | е | e ₁ | L | L ₁ ⁽¹⁾ max. |
|------|------------|--------------|----------------|--------------|------------|------------|------------|------|----------------|--------------|---------------------------------------|
| mm | 5.2 5.0 | 0.48 0.40 | 0.66 0.55 | 0.45 0.38 | 4.8 4.4 | 1.7 1.4 | 4.2 3.6 | 2.54 | 1.27 | 14.5 12.7 | 2.5 |

Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

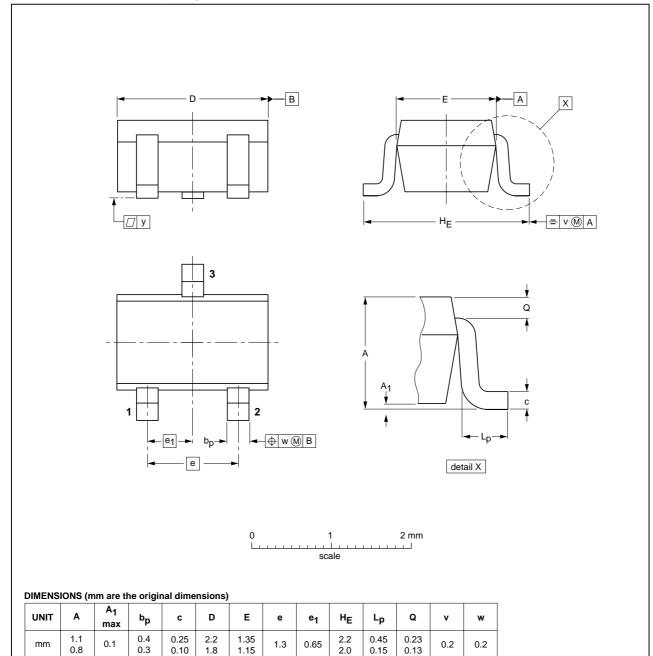
| OUTLINE VERSION | | REFER | EUROPEAN | ISSUE DATE | | |
|--------------------|-----|-------|----------|------------|------------|-----------------------------------|
| | IEC | JEDEC | JEITA | | PROJECTION | ISSUE DATE |
| SOT54 | | TO-92 | SC-43A | | | -04-06-28- 04-11-16 |

PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = open

PDTA124T series

Plastic surface-mounted package; 3 leads

SOT323



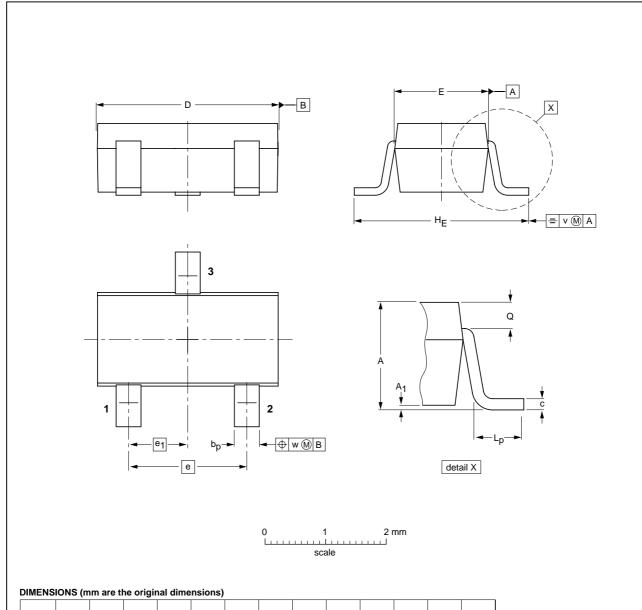
| OUTLINE VERSION | | REFER | RENCES | EUROPEAN | | |
|--------------------|-----|-------|--------|------------|---------------------------------|--|
| | IEC | JEDEC | JEITA | PROJECTION | ISSUE DATE | |
| SOT323 | | | SC-70 | | 04-11-04 06-03-16 | |

PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = open

PDTA124T series

Plastic surface-mounted package; 3 leads

SOT346



| UNIT | Α | A ₁ | bp | С | D | E | е | e ₁ | HE | Lp | Q | v | w |
|------|------------|----------------|--------------|--------------|------------|------------|-----|----------------|------------|------------|--------------|-----|-----|
| mm | 1.3 1.0 | 0.1 0.013 | 0.50 0.35 | 0.26 0.10 | 3.1 2.7 | 1.7 1.3 | 1.9 | 0.95 | 3.0 2.5 | 0.6 0.2 | 0.33 0.23 | 0.2 | 0.2 |

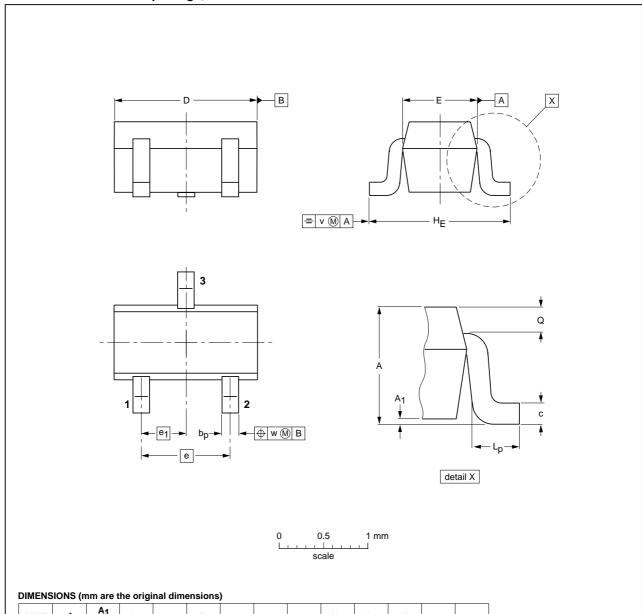
| OUTLINE | | REFER | EUROPEAN | ICCUE DATE | | |
|---------|-----|--------|----------|------------|------------|---------------------------------|
| VERSION | IEC | JEDEC | JEITA | | PROJECTION | ISSUE DATE |
| SOT346 | | TO-236 | SC-59A | | | 04-11-11 06-03-16 |

PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = open

PDTA124T series

Plastic surface-mounted package; 3 leads

SOT416



| U | NIT | Α | A ₁ max | bp | С | D | E | е | e ₁ | HE | Lp | ø | v | w |
|---|-----|--------------|-----------------------|--------------|--------------|------------|------------|---|----------------|--------------|--------------|--------------|-----|-----|
| n | nm | 0.95 0.60 | 0.1 | 0.30 0.15 | 0.25 0.10 | 1.8 1.4 | 0.9 0.7 | 1 | 0.5 | 1.75 1.45 | 0.45 0.15 | 0.23 0.13 | 0.2 | 0.2 |

| OUTLINE | | REFERENCES | | | | ISSUE DATE |
|---------|-----|------------|-------|--|------------|---------------------------------|
| VERSION | IEC | JEDEC | JEITA | | PROJECTION | ISSUE DATE |
| SOT416 | | | SC-75 | | | 04-11-04 06-03-16 |

PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = open

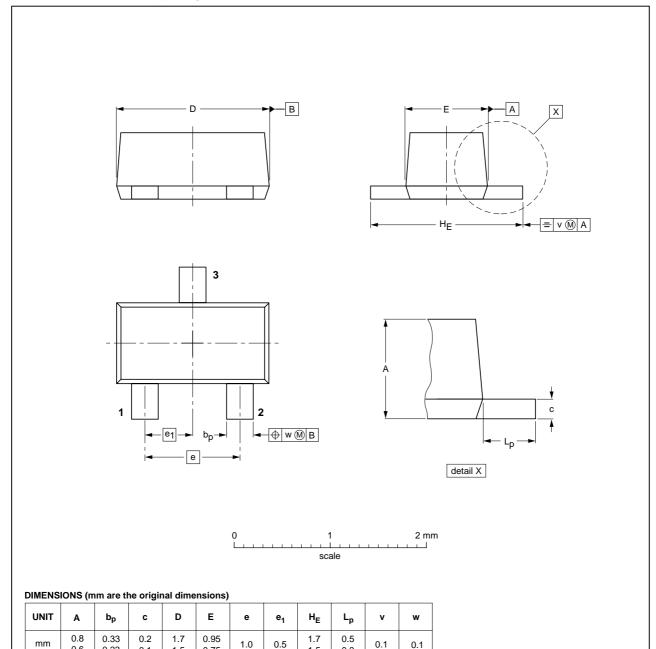
PDTA124T series

Plastic surface-mounted package; 3 leads

SOT490

05-07-28

06-03-16



| OUTLINE | | REFER | ENCES | EUROPEAN | ISSUE DATE |
|---------|-----|-------|-------|------------|------------|
| VERSION | IEC | JEDEC | JEITA | PROJECTION | ISSUE DATE |

SC-89

2004 Aug 04 11

0.6

SOT490

0.23

0.1

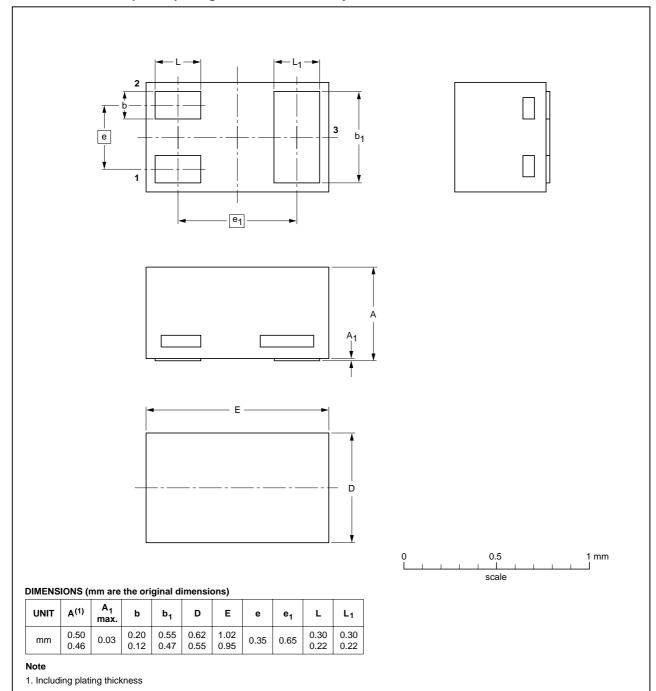
1.5

PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = open

PDTA124T series

Leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.5 mm

SOT883



| OUTLINE | | REFERENCES | | | | ISSUE DATE |
|---------|-----|------------|--------|--|------------|---------------------------------|
| VERSION | IEC | JEDEC | JEITA | | PROJECTION | ISSUE DATE |
| SOT883 | | | SC-101 | | | 03-02-05 03-04-03 |

PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = open

PDTA124T series

DATA SHEET STATUS

| DOCUMENT STATUS ⁽¹⁾ | PRODUCT STATUS ⁽²⁾ | DEFINITION |
|-----------------------------------|----------------------------------|---|
| Objective data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary data sheet | Qualification | This document contains data from the preliminary specification. |
| Product data sheet | Production | This document contains the product specification. |

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Contact information

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